

## STP03D200

## 2 kV NPN Darlington transistor

#### **Features**

- Extra high voltage capability
- High gain characteristic

### **Application**

 Active start-up network in 3 phase S.M.P.S. (see application note AN2454)

#### **Description**

The STP03D200 is made by two extra high voltage NPN transistors in Darlington configuration housed in a single package. The resulting device shows high gain performance.

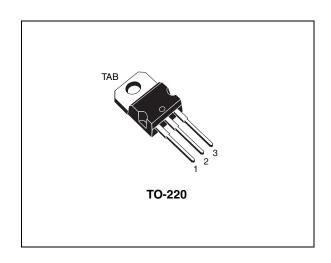


Figure 1. Internal schematic diagram

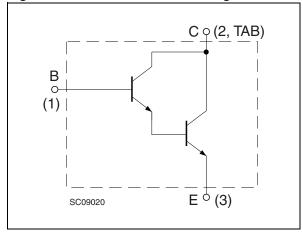


Table 1. Device summary

Order code	Marking	Package	Packaging
STP03D200	P03D200	TO-220	Tube

Electrical ratings STP03D200

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base voltage (I <sub>E</sub> = 0)	2000	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	1200	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	20	V
I <sub>C</sub>	Collector current	100	mA
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	200	mA
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> = 25 °C	40	W
T <sub>STG</sub>	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case max	3.13	°C/W

## 2 Electrical characteristics

 $T_{CASE}$  = 25  $^{\circ}C$  unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 2000 V			100	μΑ
I <sub>CEO</sub>	Collector cut-off current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 1200 V			100	μΑ
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 1 mA	1200			٧
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 μA	20			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_C = 50 \text{ mA}; \qquad I_B = 500 \text{ µ}$	A		2	V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	$I_C = 50 \text{ mA}; \qquad I_B = 500 \text{ µ}$	A		2	V
h <sub>FE</sub>	DC current gain	$I_C = 20 \text{ mA};$ $V_{CE} = 10 \text{ V}$ $I_C = 30 \text{ mA};$ $V_{CE} = 10 \text{ V}$				-

<sup>1.</sup> Pulse test: pulse duration  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %

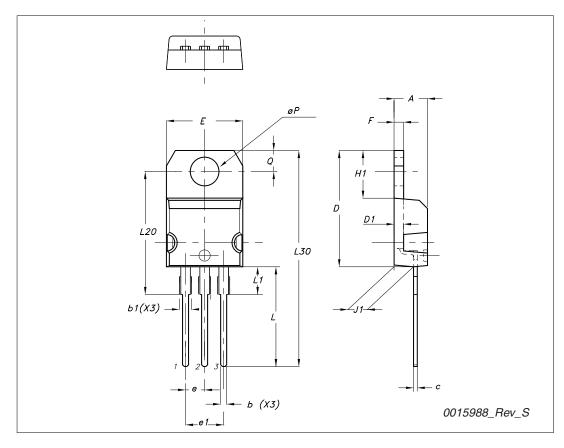
# 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Doc ID 14059 Rev 2

#### TO-220 type A mechanical data

Dim	mm			
	Min	Тур	Max	
A	4.40		4.60	
b	0.61		0.88	
b1	1.14		1.70	
С	0.48		0.70	
D	15.25		15.75	
D1		1.27		
E	10		10.40	
е	2.40		2.70	
e1	4.95		5.15	
F	1.23		1.32	
H1	6.20		6.60	
J1	2.40		2.72	
L	13		14	
L1	3.50		3.93	
L20		16.40		
L30		28.90		
ØP	3.75		3.85	
Q	2.65		2.95	



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Revision history STP03D200

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
22-Oct-2007	1	Initial release.
19-Feb-2010	2	Document status promoted from preliminary data to datasheet, modified h <sub>FE</sub> minimum values <i>Table 4 on page 3</i> .

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